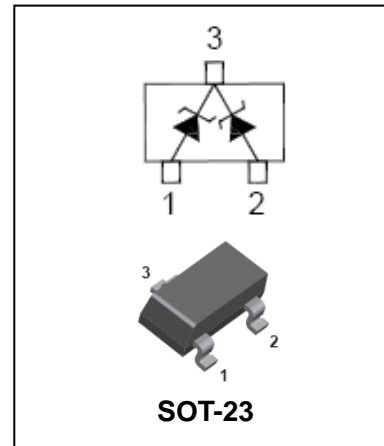


## Silicon Planar Zener Diodes

## BZX84C2V4CC - BZX84C51CC

### FEATURES

- Zener breakdown voltage range - 2.4V to 51V
- Package designed for optimal automated board assembly
- Small package size for high density applications



### ORDERING INFORMATION

Type No.	Marking	Package Code
BZX84C2V4CC - BZX84C51CC□	See Table on page2	SOT-23

□: none is for Lead Free package;  
“G” is for Halogen Free package.

### MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Value	Unit
Power Dissipation	$P_d$	350	mW
Thermal Resistance, Junction to Ambient <sup>1)</sup>	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range	$T_j, T_{stg}$	-65 to +150	°C

1) Alumina = 0.4\*0.3\*0.024 in,99.5% alumina

## Silcon Planar Zener Diodes

## BZX84C2V4CC - BZX84C51CC

Electrical Characterisilcs @ Ta=25°C unless otherwise specified, V<sub>F</sub><0.9V at I<sub>F</sub>=10

Type	Marking Code	Zener Voltage Range <sup>1)</sup>	Dynamic Resistance	Reverse Leakage Current	I <sub>ZT</sub> (mA)	Z <sub>ZT</sub> Max.(Ω)	I <sub>R</sub> Max(μA) at V <sub>R</sub> (V)	
		Min	Nom	Max				
BZX84C2V4CC	JH	2.2	2.4	2.6	5	100	50	1
BZX84C2V7CC	JJ	2.5	2.7	2.9	5	100	20	1
BZX84C3V0CC	JK	2.8	3	3.2	5	95	10	1
BZX84C3V3CC	JM	3.1	3.3	3.5	5	95	5	1
BZX84C3V6CC	JN	3.4	3.6	3.8	5	90	5	1
BZX84C3V9CC	JP	3.7	3.9	4.1	5	90	3	1
BZX84C4V3CC	JR	4	4.3	4.6	5	90	3	1
BZX84C4V7CC	JX•	4.4	4.7	5	5	80	3	2
BZX84C5V1CC	JY	4.8	5.1	5.4	5	60	2	2
BZX84C5V6CC	JZ	5.2	5.6	6	5	40	1	2
BZX84C6V2CC	KA	5.8	6.2	6.6	5	10	3	4
BZX84C6V8CC	KB	6.4	6.8	7.2	5	15	2	4
BZX84C7V5CC	KC	7	7.5	7.9	5	15	1	5
BZX84C8V2CC	KD	7.7	8.2	8.7	5	15	0.7	5
BZX84C9V1CC	KE	8.5	9.1	9.6	5	15	0.5	6
BZX84C10CC	KF	9.4	10	10.6	5	20	0.2	7
BZX84C11CC	KH	10.4	11	11.6	5	20	0.1	8
BZX84C12CC	KJ	11.4	12	12.7	5	25	0.1	8
BZX84C13CC	KK	12.4	13	14.1	5	30	0.1	8
BZX84C15CC	KM	14.3	15	15.8	5	30	0.05	10.5
BZX84C16CC	KN	15.3	16	17.1	5	40	0.05	11.2

## Silicon Planar Zener Diodes

## BZX84C2V4CC - BZX84C51CC

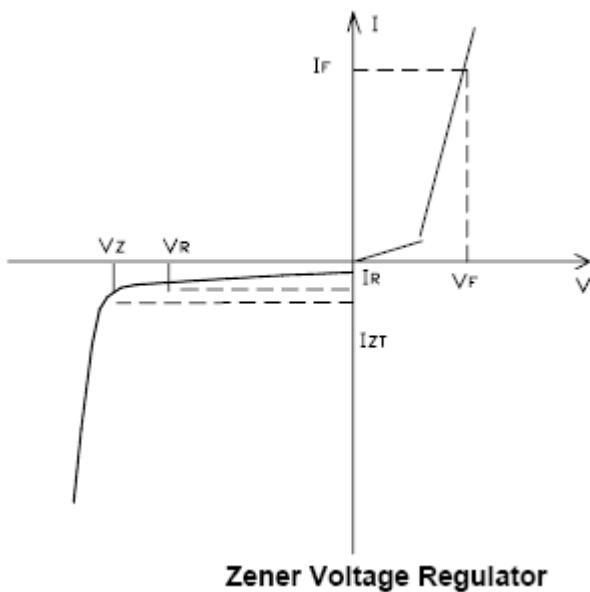
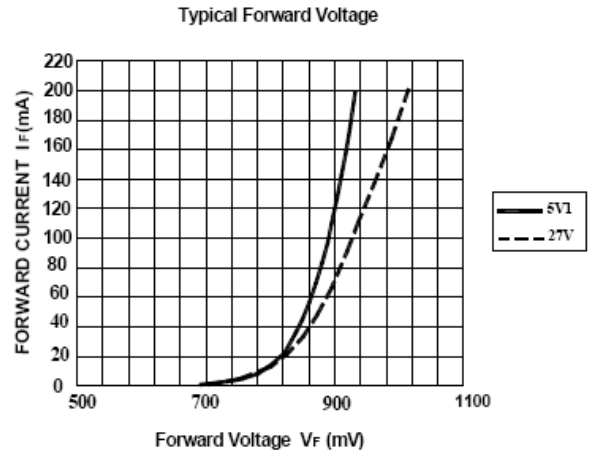
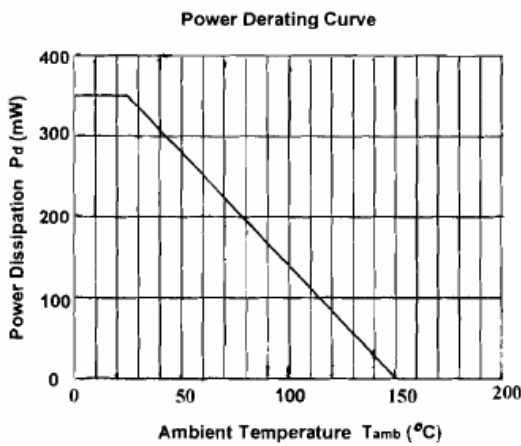
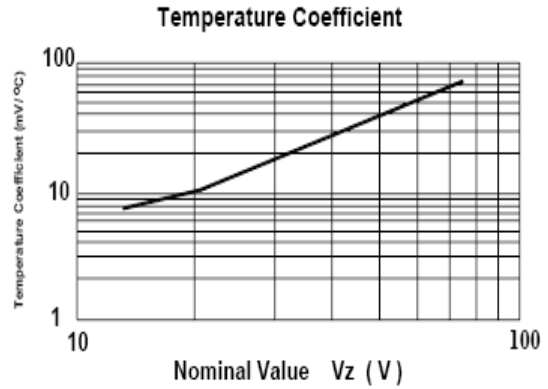
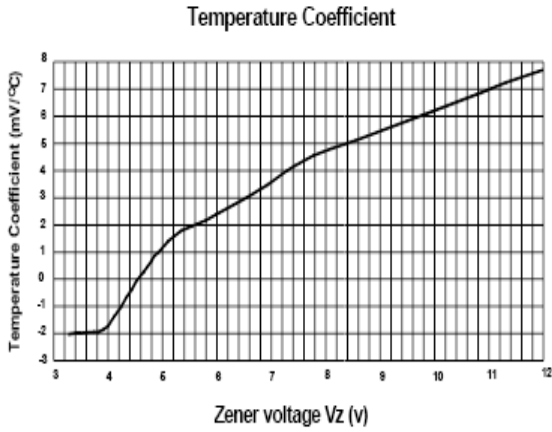
Type	Marking Code	Zener Voltage Range <sup>1)</sup>	Dynamic Resistance	Reverse Leakage Current	I <sub>ZT</sub> (mA)	Z <sub>ZT</sub> Max.(Ω)	I <sub>R</sub> Max(μA) at V <sub>R</sub> (V)	
		Min	Nom	Max				
BZX84C18CC	KP	16.8	18	19.1	5	45	0.05	12.6
BZX84C20CC	KR	18.8	20	21.2	5	55	0.05	14
BZX84C22CC	KX	20.8	22	23.3	5	55	0.05	15.4
BZX84C24CC	KY	22.8	24	25.6	5	70	0.05	16.8
BZX84C27CC	KZ	25.1	27	28.9	2	80	0.05	18.9
BZX84C30CC	MA	28	30	32	2	80	0.05	21
BZX84C33CC	MB	31	33	35	2	80	0.05	23.1
BZX84C36CC	MC	34	36	38	2	90	0.05	25.2
BZX84C39CC	MD	37	39	41	2	130	0.05	27.3
BZX84C43CC	ME	40	43	46	2	150	0.05	30.1
BZX84C47CC	MF	44	47	50	2	170	0.05	32.9
BZX84C51CC	MH	48	51	54	2	180	0.05	35.7

1) Tested with pulses tp=20ms

**Silcon Planar Zener Diodes**

**BZX84C2V4CC - BZX84C51CC**

TYPICAL CHARACTERISTICS @  $T_a=25^{\circ}\text{C}$  unless otherwise specified



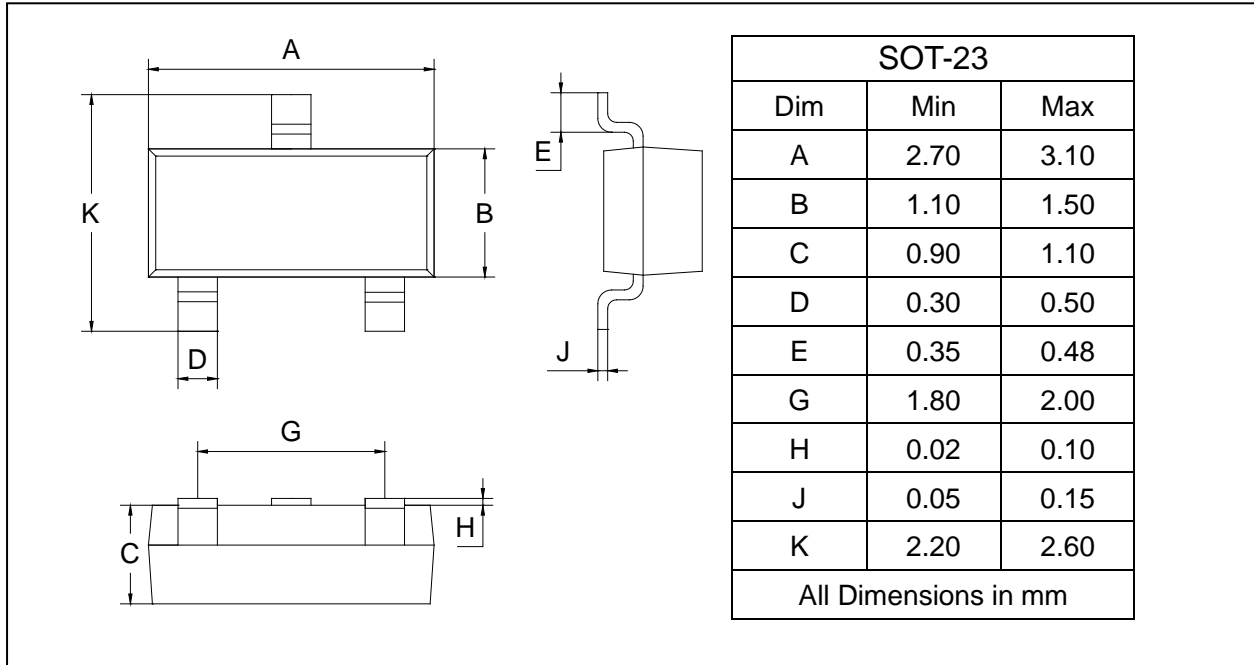
## Silicon Planar Zener Diodes

## BZX84C2V4CC - BZX84C51CC

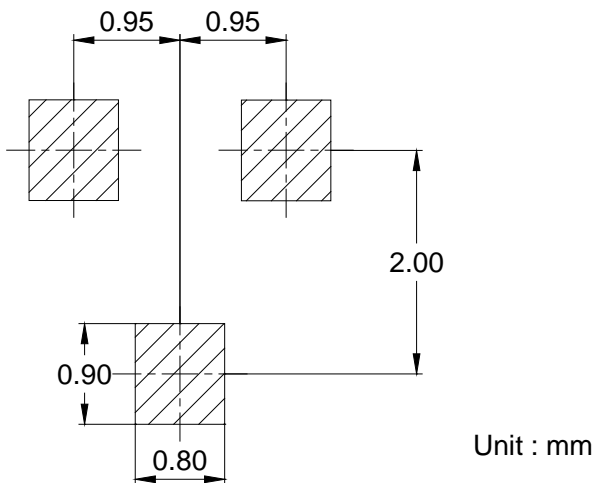
### PACKAGE OUTLINE

Plastic surface mounted package

SOT-23



### SOLDERING FOOTPRINT



### PACKAGE INFORMATION

Device	Package	Shipping
BZX84C2V4CC-BZX84C51CC	SOT-23	3000/Tape&Reel